

AMMP-6442

37- 40 GHz, 1W Linear Power Amplifier
in SMT Package



Data Sheet



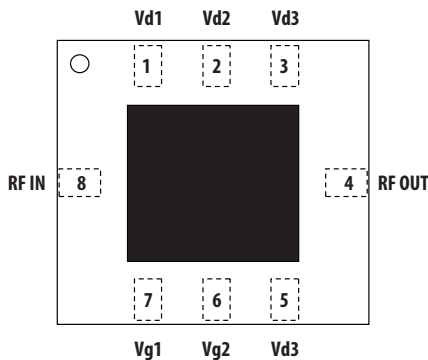
Description

The AMMP-6442 MMIC is a 1W linear power amplifier in a surface mount package designed for use in transmitters that operate at frequencies between 37GHz and 40GHz. In the operational band, it provides 30dBm of output power (P-1dB) and 23dB of small-signal gain. This PA is also designed for high linear applications with typical performance of 36dBm OIP3 at 18dBm SCL output.

Applications

- Point-to-Point Radio Systems
- mmW Communications

Package Diagram



Note:
1. This MMIC uses depletion mode pHEMT devices.
Negative supply is used for DC gate biasing.

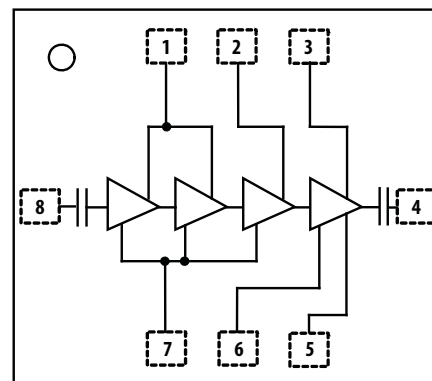
Features

- 5x5mm SMT package
- 1 watt output power
- 50 Ω match on input and output
- ESD protection (50V MM, and 250V HBM)

Typical Performance (Vd = 5V, Id(q) = 0.7A)

- Frequency range 37 to 40 GHz
- Small signal Gain of 23dB (Typ.)
- Output power @P-1 of 30dBm (Typ.)
- Input and Output return losses -8dB
- OIP3 of 35dBm @Po=18dBm (scl)

Functional Block Diagram



| Pin | Function |
|-----|----------|
| 1 | Vd1 |
| 2 | Vd2 |
| 3 | Vd3 |
| 4 | RF OUT |
| 5 | Vd3 |
| 6 | Vg2 |
| 7 | Vg1 |
| 8 | RF IN |

RoHS-Exemption



Please refer to hazardous substances table on page 7.



Attention: Observe Precautions for handling electrostatic sensitive devices.

ESD Machine Model (Class A): 50V
ESD Human Body Model (Class 1A): 250V

Refer to Avago Application Note A004R:
Electrostatic Discharge Damage and Control.

Note: MSL Rating = Level 2A

Electrical Specifications

1. Small/Large -signal data measured in a fully de-embedded test fixture form TA = 25°C.
2. Pre-assembly into package performance verified 100% on-wafer per AMMC-6442 published specifications.
3. This final package part performance is verified by a functional test correlated to actual performance at one or more frequencies.
4. Specifications are derived from measurements in a 50 Ω test environment. Aspects of the amplifier performance may be improved over a more narrow bandwidth by application of additional conjugate, linearity, or low noise (Гopt) matching.

Table 1. RF Electrical Characteristics

TA=25°C, Vd=5.0V, Idq=0.7V, Vg=-1V, Zo=50 Ω

| Parameter | Min | Typ. | Max | Unit |
|---|-----|------|-----|------|
| Operational Frequency, Freq | 37 | | 40 | GHz |
| Small-signal Gain, Gain | 20 | 23 | | dB |
| Output Power at 1dB Gain Compression, P-1dB | 28 | 30 | | dBm |
| Relative Third Order Inter-modulation level (Δf=10MHz, Po=+12dBm, SCL), IM3 | | 36 | | dBc |
| Input Return Loss, Rlin | | 8 | | dB |
| Output Return Loss, Rlout | | 8 | | dB |
| Reverse Isolation, Isolation | | 45 | | dB |

Table 2. Recommended Operating Range

1. Ambient operational temperature TA = 25°C unless otherwise noted.
2. Channel-to-backside Thermal Resistance (Tchannel (Tc) = 34°C) as measured using infrared microscopy. Thermal Resistance at backside temperature (Tb) = 25°C calculated from measured data.

| Description | Min. | Typical | Max. | Unit | Comments |
|-----------------------------------|------|---------|------|------|--------------------------------|
| Drain Supply Current, Idq | | 700 | | mA | Vd = 5V, Vg set for Id Typical |
| Gate Supply Operating Voltage, Vg | -1.3 | -1 | -0.7 | V | Idq=700mA |

Table 3. Thermal Properties

| Parameter | Test Conditions | Value |
|--|--|---------------|
| Channel Temperature, Tch | | Tch=150 °C |
| Thermal Resistance ^[1] (Channel-to-Base Plate), θch-bs | Channel-to-backside Thermal Resistance Tchannel(Tc)=34°C Thermal Resistance at backside temperature Tb=25°C | θJc = 12 °C/W |

Note:

1. Assume AnPb soldering to an evaluation RF module at 90.5 °C base plate temperatures.

Absolute Minimum and Maximum Ratings

Table 4. Minimum and Maximum Ratings^[1]

| Description Pin | Min. | Max. | Unit | Comments |
|------------------------------|------|------|------|-------------------|
| Drain Supply Voltage, Vd | | 5.5 | V | |
| Gate Supply Voltage, Vg | -2 | 0 | | |
| Power Dissipation, P-D | | 6 | | |
| CW Input Power, Pin | | 20 | dBm | CW |
| Channel Temperature | | +150 | °C | |
| Storage Temperature | -65 | +155 | °C | |
| Maximum Assembly Temperature | | +260 | °C | 30 second maximum |

Notes:

1. Operation in excess of any one of these conditions may result in permanent damage to this device.

Typical Performance (Data was obtained from a 2.4mm connector based test fixture and includes connector and board losses. Connector and board loss is approximately 0.75dB at input and output ports for an approximate total of 1.5dB.)

($T_A = 25^\circ\text{C}$, $V_{dd} = 5\text{V}$, $I_{d(q)} = 0.7\text{A}$, $V_g = -1\text{V}$, $Z_{in} = Z_{out} = 50\ \Omega$)

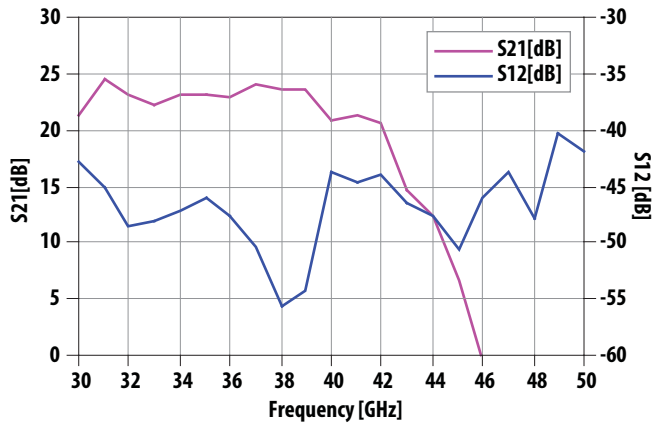


Figure 1. Typical gain and reverse isolation

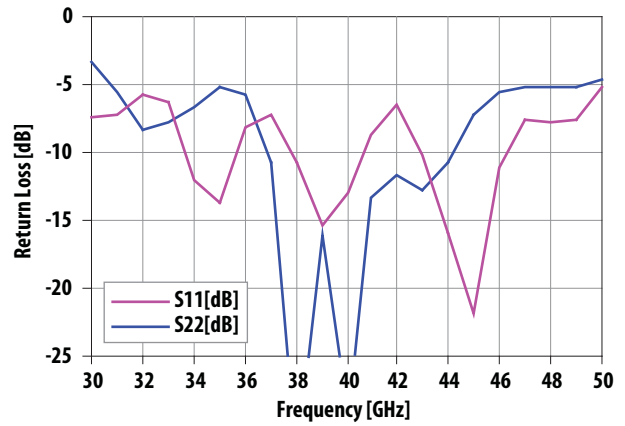


Figure 2. Typical return Loss (input and output)

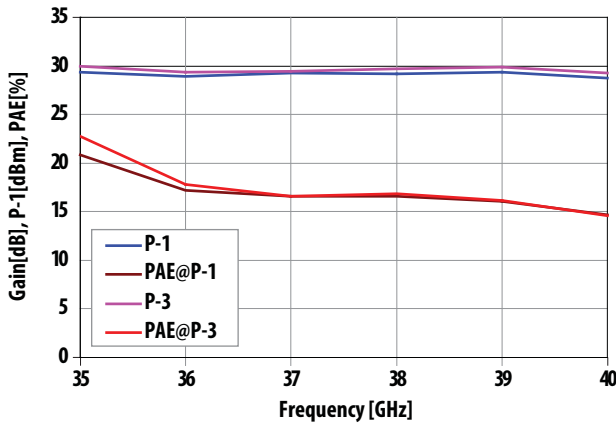


Figure 3. Typical output power (P-1 and P-3) vs. frequency

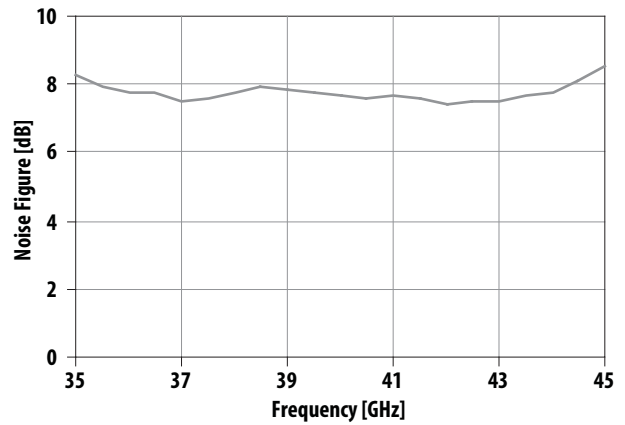


Figure 4. Typical noise figure

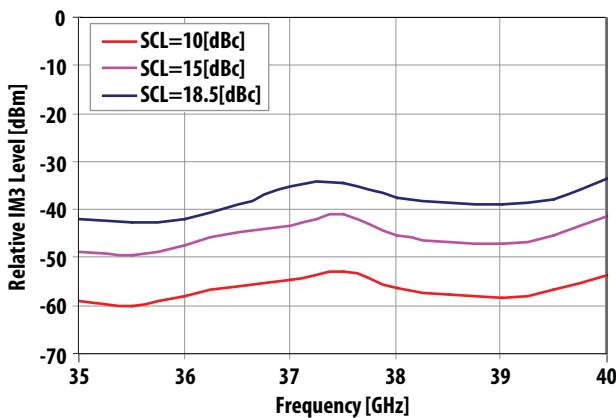


Figure 5. Typical third order inter-modulation product level vs. frequency at different single carrier output level (SCL)

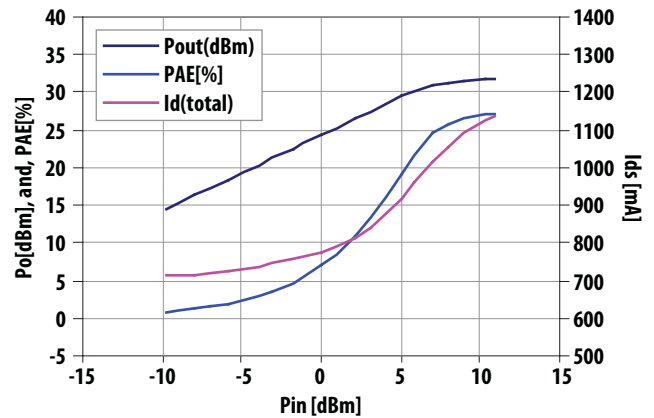


Figure 6. Typical output power, PAE, and total drain current versus Input power at 38GHz

Typical over temperature dependencies

($T_A = 25^\circ\text{C}$, $V_{dd} = 5\text{V}$, $I_{dq} = 0.7\text{A}$, $V_g = -1\text{V}$, $Z_{in} = Z_{out} = 50\ \Omega$)

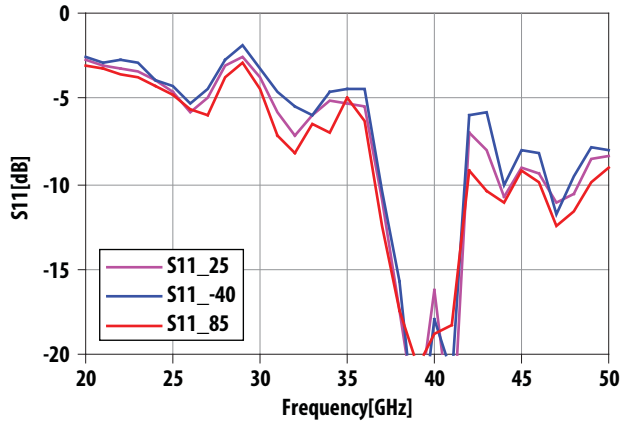


Figure 7. Typical S11 over temperature

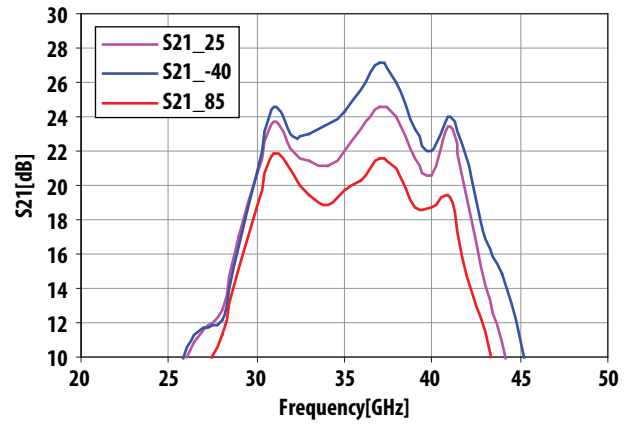


Figure 8. Typical Gain over temperature

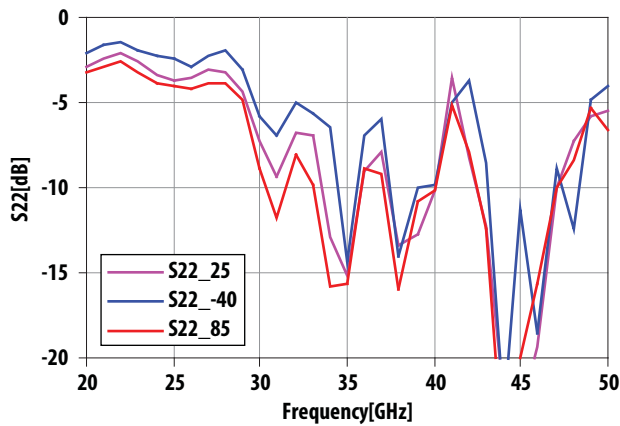


Figure 9. Typical S22 over temperature

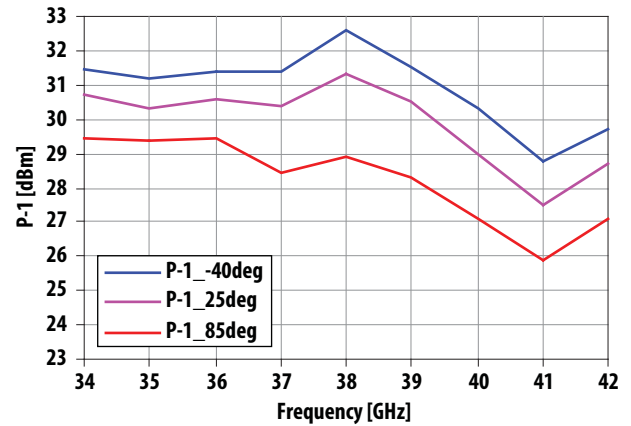


Figure 10. Typical P1 over temperature

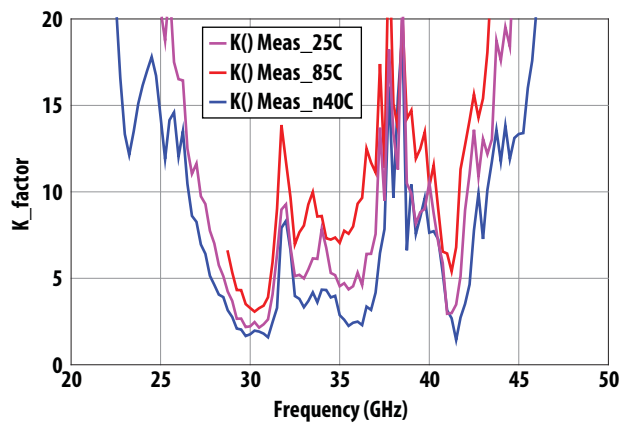


Figure 11. Typical K-factor over temperature

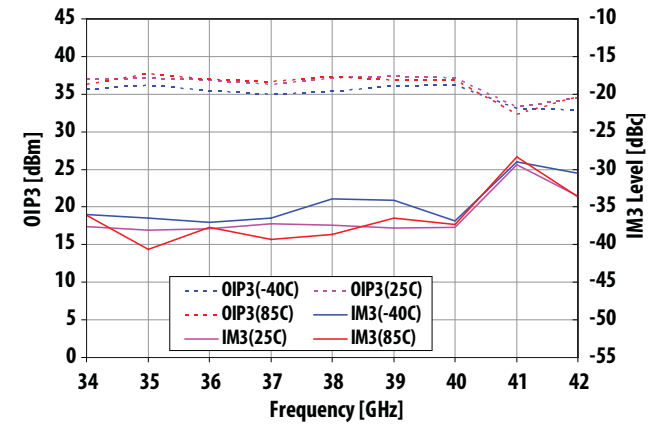


Figure 12. Typical IM3 level over temperature at $P_o=18\text{dBm}$, SCL

Typical Scattering Parameters [1], ($T_A = 25^\circ\text{C}$, $V_d = 5\text{ V}$, $I_D = 0.7\text{ A}$, $Z_{in} = Z_{out} = 50\ \Omega$)

| Freq | S11 [dB] | S11 Mag. | S11 Ang. | S21 [dB] | S21 Mag. | S21 Ang. | S12 [dB] | S12 Mag. | S12 Ang. | S22 [dB] | S22 Mag. | S22 Ang. |
|------|----------|----------|----------|----------|----------|----------|----------|----------|----------|----------|----------|----------|
| 20 | -2.90 | 0.72 | 164.53 | -23.81 | 0.06 | -141.01 | -48.88 | 3.60E-03 | -57.97 | -2.69 | 0.73 | 21.40 |
| 21 | -3.00 | 0.71 | 86.65 | -15.74 | 0.16 | 115.71 | -52.28 | 2.43E-03 | -104.05 | -2.41 | 0.76 | -70.16 |
| 22 | -3.08 | 0.70 | 4.08 | -7.22 | 0.44 | 0.83 | -45.40 | 5.37E-03 | 152.36 | -2.25 | 0.77 | -161.69 |
| 23 | -3.18 | 0.69 | -87.20 | 0.27 | 1.03 | -131.23 | -46.50 | 4.73E-03 | 103.80 | -2.68 | 0.73 | 112.41 |
| 24 | -3.62 | 0.66 | 176.98 | 4.45 | 1.67 | 92.82 | -48.17 | 3.90E-03 | -13.03 | -3.39 | 0.68 | 32.65 |
| 25 | -4.52 | 0.59 | 84.30 | 7.24 | 2.30 | -36.02 | -48.90 | 3.59E-03 | -66.94 | -3.55 | 0.66 | -45.60 |
| 26 | -5.00 | 0.56 | -8.28 | 9.35 | 2.93 | -154.65 | -50.90 | 2.85E-03 | -147.71 | -2.98 | 0.71 | -125.74 |
| 27 | -4.11 | 0.62 | -104.27 | 11.05 | 3.57 | 81.71 | -48.42 | 3.79E-03 | 176.54 | -2.72 | 0.73 | 155.15 |
| 28 | -3.00 | 0.71 | 168.96 | 13.11 | 4.52 | -26.13 | -48.48 | 3.77E-03 | 100.75 | -3.20 | 0.69 | 77.20 |
| 29 | -2.20 | 0.78 | 90.69 | 16.36 | 6.57 | -143.75 | -44.95 | 5.66E-03 | 16.82 | -4.92 | 0.57 | -11.91 |
| 30 | -3.25 | 0.69 | 7.32 | 21.27 | 11.57 | 95.82 | -42.75 | 7.28E-03 | -67.62 | -7.33 | 0.43 | -126.78 |
| 31 | -5.62 | 0.52 | -81.47 | 24.48 | 16.76 | -48.77 | -45.14 | 5.53E-03 | -173.22 | -7.23 | 0.44 | 132.40 |
| 32 | -8.31 | 0.38 | 151.65 | 23.09 | 14.27 | 172.96 | -48.44 | 3.78E-03 | 113.12 | -5.77 | 0.51 | 54.23 |
| 33 | -7.80 | 0.41 | 55.51 | 22.16 | 12.83 | 59.22 | -48.10 | 3.94E-03 | 83.43 | -6.33 | 0.48 | -12.99 |
| 34 | -6.69 | 0.46 | -3.34 | 23.03 | 14.18 | -64.46 | -47.20 | 4.36E-03 | 14.73 | -12.04 | 0.25 | -100.71 |
| 35 | -5.11 | 0.56 | -64.50 | 23.07 | 14.25 | 169.26 | -46.03 | 5.00E-03 | -72.16 | -13.67 | 0.21 | 6.05 |
| 36 | -5.77 | 0.51 | -136.84 | 22.91 | 13.97 | 48.13 | -47.62 | 4.16E-03 | -147.24 | -8.21 | 0.39 | -77.65 |
| 37 | -10.68 | 0.29 | 144.16 | 24.12 | 16.07 | -78.82 | -50.37 | 3.03E-03 | 131.49 | -7.25 | 0.43 | -146.43 |
| 38 | -32.53 | 0.02 | 70.22 | 23.59 | 15.11 | 148.85 | -55.62 | 1.66E-03 | 37.70 | -10.74 | 0.29 | 121.48 |
| 39 | -16.09 | 0.16 | 123.23 | 23.65 | 15.23 | 12.30 | -54.20 | 1.95E-03 | -76.46 | -15.37 | 0.17 | -4.18 |
| 40 | -29.19 | 0.03 | 44.21 | 20.79 | 10.95 | -116.29 | -43.80 | 6.46E-03 | 70.75 | -13.01 | 0.22 | -123.56 |
| 41 | -13.30 | 0.22 | -59.99 | 21.33 | 11.66 | 112.89 | -44.57 | 5.91E-03 | -75.57 | -8.63 | 0.37 | 173.01 |
| 42 | -11.59 | 0.26 | 149.87 | 20.57 | 10.68 | -35.23 | -43.90 | 6.39E-03 | 146.83 | -6.41 | 0.48 | 75.90 |
| 43 | -12.74 | 0.23 | 70.60 | 14.55 | 5.34 | -173.04 | -46.59 | 4.69E-03 | 7.19 | -10.12 | 0.31 | 4.46 |
| 44 | -10.80 | 0.29 | 4.51 | 12.27 | 4.10 | 48.86 | -47.60 | 4.17E-03 | -74.19 | -15.97 | 0.16 | -73.99 |
| 45 | -7.28 | 0.43 | -68.05 | 6.64 | 2.15 | -95.90 | -50.63 | 2.94E-03 | 175.00 | -21.81 | 0.08 | -64.83 |
| 46 | -5.57 | 0.53 | -149.37 | -0.54 | 0.94 | 129.12 | -45.96 | 5.04E-03 | 157.54 | -11.06 | 0.28 | -107.83 |
| 47 | -5.11 | 0.56 | 128.69 | -7.71 | 0.41 | 4.98 | -43.66 | 6.56E-03 | 42.47 | -7.63 | 0.42 | 164.84 |
| 48 | -5.10 | 0.56 | 40.23 | -14.75 | 0.18 | -116.43 | -47.75 | 4.10E-03 | -27.21 | -7.78 | 0.41 | 65.52 |
| 49 | -5.16 | 0.55 | -55.86 | -21.51 | 0.08 | 127.74 | -40.36 | 9.59E-03 | -151.21 | -7.59 | 0.42 | -65.16 |
| 50 | -4.69 | 0.58 | -154.92 | -33.07 | 0.02 | 27.73 | -41.94 | 8.00E-03 | 170.09 | -5.13 | 0.55 | -177.64 |

Note:

1. Data obtained from 2.4-mm connector based modules, and this data is including connector loss, and board loss. The measurement reference plane is at the RF connectors.

Biasing and Operation

Recommended quiescent DC bias condition for optimum power and linearity performances is $V_d=5$ volts with V_g (-1V) set for $I_d=700$ mA. Minor improvements in performance are possible depending on the application. The drain bias voltage range is 3 to 5V. A single DC gate supply connected to V_g will bias all gain stages. Muting can be accomplished by setting V_g to the pinch-off voltage V_p (-2V).

A typical DC bias configuration is shown in Figure 13. V_d3 may be biased from either side (Pin 3 or Pin 5). The RF input and output ports are DC decoupled internally. No ground wires are needed since ground connections are made with plated through-holes to the backside of the device.

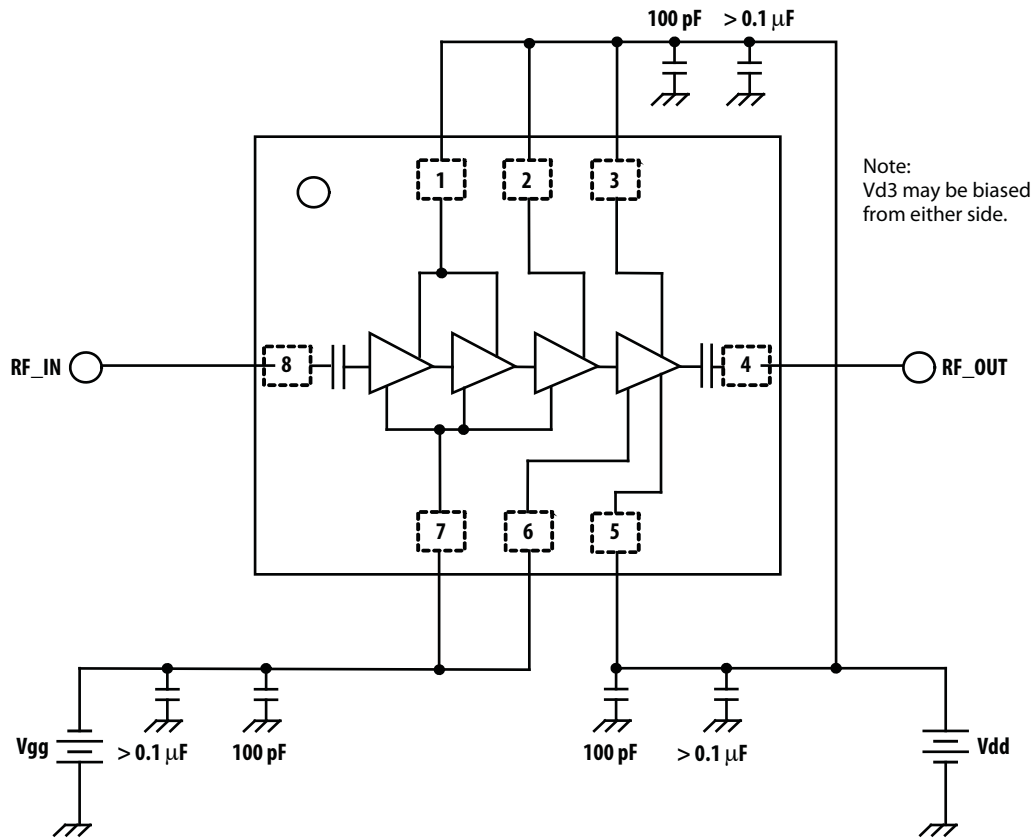


Figure 13. Schematic and recommended assemble example

Note: No RF performance degradation is seen due to ESD up to 250V HBM and 50V MM. The DC characteristics in general show increased leakage at lower ESD discharge voltages. The user is reminded that this device is ESD sensitive and needs to be handled with all necessary ESD protocols.

AMMP-64xx Part Number Ordering Information

| Part Number | Devices Per Container | Container |
|---------------|-----------------------|----------------|
| AMMP-64xx-BLK | 10 | Antistatic bag |
| AMMP-64xx-TR1 | 100 | 7" Reel |
| AMMP-64xx-TR2 | 500 | 7" Reel |

Package Dimension, PCB Layout and Tape and Reel information

Please refer to Avago Technologies Application Note 5521, AMxP-xxxx production Assembly Process (Land Pattern B).



Names and Contents of the Toxic and Hazardous Substances or Elements in the Products 产品中有毒有害物质或元素的名称及含量

| Part Name 部件名称 | Toxic and Hazardous Substances or Elements 有毒有害物质或元素 | | | | | |
|-------------------|---|---------------------------|---------------------------|---|---|--|
| | Lead (Pb) 铅 (Pb) | Mercury (Hg) 汞 (Hg) | Cadmium (Cd) 镉 (Cd) | Hexavalent (Cr(VI)) 六价 铬 (Cr(VI)) | Polybrominated biphenyl (PBB) 多 溴联苯 (PBB) | Polybrominated diphenylether (PBDE) 多溴二苯醚 (PBDE) |
| 100pF capacitor | x | o | o | o | o | o |

o: indicates that the content of the toxic and hazardous substance in all the homogeneous materials of the part is below the concentration limit requirement as described in SJ/T 11363-2006.
x: indicates that the content of the toxic and hazardous substance in at least one homogeneous material of the part exceeds the concentration limit requirement as described in SJ/T 11363-2006.
(The enterprise may further explain the technical reasons for the "x" indicated portion in the table in accordance with the actual situations.)

o: 表示该有毒有害物质在该部件所有均质材料中的含量均在 SJ/T 11363-2006 标准规定的限量要求以下。
x: 表示该有毒有害物质至少在该部件的某一均质材料中的含量超出 SJ/T 11363-2006 标准规定的限量要求。
(企业可在此处, 根据实际情况对上表中打"x"的技术原因进行进一步说明。)

Note: EU RoHS compliant under exemption clause of "lead in electronic ceramic parts (e.g. piezoelectronic devices)"

For product information and a complete list of distributors, please go to our web site: www.avagotech.com

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